

Section 3: MOSFETs

N-Channel Devices

BV_{DSS} below 40V (Preliminary Data)

The performance of this range of HDMOS devices has been optimised for low on-resistance and fast switching. The devices are targeted for use in switching applications within the portable equipment market. The small surface mount packages available for this range make them ideal in

applications when space is at a premium. Typical functions that will benefit from these devices include DC-DC conversion, motor control, battery and power management and load switching.

Part No.	BV_{DSS} V	I_D A	P_D W	$R_{DS(on)}$ Ω		$R_{DS(on)}$ Ω		Config.	Package
				Max	at V_{GS}	Max	at V_{GS} V		
ZXM64N03X	30	3.9	1.8	0.035	10	0.060	4.5	single	MSOP8
ZXM62N03E6	30	2.2	1.7	0.1	10	0.2	4.5	single	SOT23-6
ZXMD63N03X	30	1.8	1.25	0.135	10	0.222	4.5	dual	MSOP8
ZXM61N03F	30	1.2	0.625	0.2	10	0.4	4.5	single	SOT23
ZXM64N02X	20	3.9	1.8	0.035	4.5	0.050	2.7	single	MSOP8
ZXM62N02E6	20	2.2	1.7	0.1	4.5	0.17	2.7	single	SOT23-6
ZXMD63N02X	20	1.8	1.25	0.135	4.5	0.2	2.7	dual	MSOP8
ZXM61N02F	20	1.2	0.625	0.2	4.5	0.35	2.7	single	SOT23

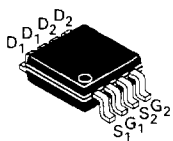
Note:

1) 30V devices have $\pm 20V$ gate-source rating and 20V devices have $\pm 12V$ gate-source ratings.

TSSOP8, SO8, and SOT223 packaged parts to follow

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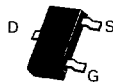
MSOP8 Dual



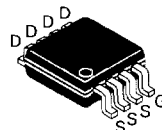
SOT23-6



SOT23



MSOP8



N-Channel

